

DG143/144/146

SPDT JFET

Analog Switches

FEATURES

- Low Standby Power ($< 1 \mu\text{W}$)
- Bipolar Drivers
- Constant $r_{DS(ON)}$ Over Signal Range
- High Off Isolation ($> 60 \text{ dB}$ @ 1 MHz)

BENEFITS

- Minimizes Standby Power Requirement
- Better Radiation Tolerance
- Less Signal Distortion
- Higher Frequency Switching

APPLICATIONS

- Portable and Battery Powered Systems
- Switching in Satellite Applications
- Low Distortion Circuits
- High Frequency Switching Circuits

DESCRIPTION

The DG143, DG144, and DG146 are precision single-pole double-throw analog switches designed for use in low distortion, high frequency circuits.

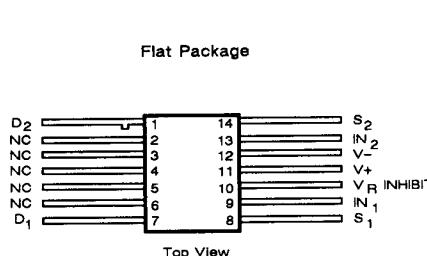
ON resistance of the DG143 is $< 80 \Omega$, the DG144 $< 30 \Omega$ and the DG146 is $< 10 \Omega$ and ON shunt leakage for all three is $< 2 \text{nA}$. With the driver in the "switch OFF" state, total power consumption is $< 750 \mu\text{W}$. By using the JFET process, all three analog switches are relatively radiation tolerant.

The DG143, DG144 and DG146 each contain two junction-type field-effect transistors (JFETs) designed to function as single-pole double-throw electronic switches. Level-shifting drivers enable low-level inputs (2 to 3 V) to control the ON-OFF state of the switches. The driver inputs are connected differentially, therefore with input IN₂

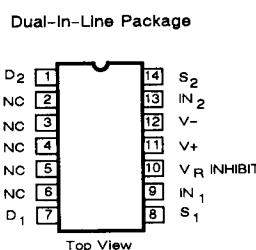
connected to a 2.5 voltage reference, a positive logic "0" at the input IN₁ will turn switch 1 OFF and switch 2 ON. A positive logic "1" at IN₁ will turn switch 1 ON and switch 2 OFF. The normally grounded V_R terminal may be used as an "inhibit" terminal, in which case all switches may be held OFF with a positive voltage applied to V_R. In the ON state each switch conducts equally well in either direction, and in the OFF state each switch will block voltages up to 20 V peak-to-peak.

Packaging for this series include a 14-pin side braze and flatpack options. Performance grades include both a military, A suffix (-55 to 125°C) and industrial, B suffix (-25 to 85°C) temperature range. The flatpack option is only available in the military grade.

PIN CONFIGURATION

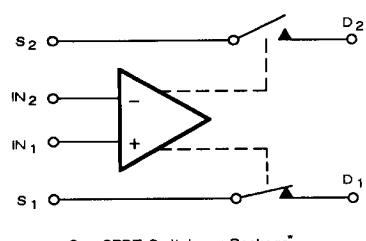


Order Numbers:
DG143AL/883, DG144AL/883
or DG146AL/883



Order Numbers:
DG143AP, DG143BP
DG144AP, DG144BP
DG146AP, DG146BP

FUNCTIONAL BLOCK DIAGRAM



Truth Table

LOGIC	SW1	SW2
0	OFF	ON
1	ON	OFF

*Switches Shown for Logic "1" Input at IN₁, and 2.5 V Reference at IN₂.

Not Recommended for New Designs

ABSOLUTE MAXIMUM RATINGS

V ₊ to V ₋ , V _D or V _S	35 V	Current, (Any Terminal)	30 mA
V _D or V _S to V ₋	35 V	Storage Temperature	-65 to 150°C
V _D to V _S	±25 V	Operating Temperature (A Suffix)	-55 to 125°C
V ₊ to V _R	25 V	(B Suffix)	-25 to 85°C
V ₊ to V _{IN1} or V _{IN2}	25 V	Power Dissipation*	
V _R to V ₋	25 V	Flat Package**	750 mW
V _{IN1} to V _{IN2}	±5 V	14-Pin DIP***	825 mW
V _{IN1} or V _{IN2} to V _R	±5 V	* All leads welded or soldered to PC board.	
V _{IN1} or V _{IN2} to V ₋	30 V	** Derate 10 mW/°C above 75°C.	
		*** Derate 11 mW/°C above 75°C.	

ELECTRICAL CHARACTERISTICS^a								DG143	
PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified:		LIMITS				UNIT	
		V ₊ = 12 V V ₋ = -18 V V _R = 0 V V _{IR,2} = 2.5 V	TEMP	MIN ^b	MAX ^b	B SUFFIX -25 to 85°C	MIN ^b	MAX ^b	
SWITCH									
Analog Signal Range ^c	V _{ANALOG}		1,2,3		-10	10	-8	8	V
Drain-Source ON Resistance	r _{DS(ON)}	I _S = -10 mA V _{IN1} = 3 V (SW1 ON) V _{IN1} = 2 V (SW2 ON)	V _D = 10 V V _D = 8 V	1, 2	30 35		80 150		Ω
			V _S = 10 V V _D = -10 V V _S = 8 V V _D = -8 V	1, 2	0.15 0.75		1 100		
Source OFF Leakage Current	I _{S(OFF)}	V _{IN1} = 2 V (SW1 OFF) V _{IN1} = 3 V (SW2 OFF)	V _D = 10 V V _S = -10 V V _D = 8 V V _S = -8 V	1, 2	0.03 0.15		1 100		nA
				1, 2					
Drain OFF Leakage Current	I _{D(OFF)}	V _{IN1} = 3 V (SW1 ON) V _{IN1} = 2 V (SW2 ON)	V _D = 10 V V _S = -10 V V _D = 8 V V _S = -8 V	1, 2	-0.05 -0.12	-2 -100			nA
				1, 2			-5 -100		
Channel ON Leakage Current	I _{D(ON)} + I _{S(ON)}	V _{IN1} = 3 V (SW1 ON) V _{IN1} = 2 V (SW2 ON)	V _D = V _S = -10 V V _D = V _S = -8 V	1, 2	0.001		0.1 2	4 4	μA
				1, 2	0.001		0.1 2	4 4	
INPUT									
Input 1 Current Input 1 Voltage LOW	I _{IN1L}	V _{IN1} = 2 V	1, 2	0.001		0.1 2		4 4	μA
Input 2 Current Input 2 Voltage LOW	I _{IN2L}	V _{IN2} = 2 V, V _{IN1} = 2.5 V	1, 2	0.001		0.1 2		4 4	

Not Recommended for New Designs

ELECTRICAL CHARACTERISTICS^a

DG143

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 12\text{ V}$ $V_- = -18\text{ V}$ $V_R = 0\text{ V}$ $V_{IN2} = 2.5\text{ V}$	LIMITS						UNIT	
			1=25°C 2=125, 85°C 3=-55, -25°C		A SUFFIX -55 to 125°C		B SUFFIX -25 to 85°C			
		TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b	MAX ^b			
INPUT (Cont'd)										
Input 1 Current Input 1 Voltage HIGH	I _{IN1H}		V _{IN1} = 3 V	1,2 3	25 35		60 120		100 150	μA
Input 2 Current Input 2 Voltage HIGH	I _{IN2H}		V _{IN2} = 3 V, V _{IN1} = 2.5 V	1,2 3	25 35		60 120		100 150	μA
DYNAMIC										
Turn-ON Time	t _{ON}	See Switching Time Test Circuit ^e		1	0.5		0.8		1	μs
Turn-OFF Time	t _{OFF}			1	1.1		1.6		2	μs
Drain-OFF Capacitance	C _{D(OFF)}	f = 1 MHz	V _D = 0 V I _S = 0	1	2.4					pF
Source-OFF Capacitance	C _{S(OFF)}		V _S = 0 V I _D = 0	1	2.4					pF
Channel-ON Capacitance	C _{D(ON)} + C _{S(ON)}		V _D = V _S = 0 V	1	2.8					pF
OFF Isolation			R _L = 75 Ω, f = 1 MHz	1	> 60					dB
SUPPLY										
Positive Supply Current	I ₊	One Channel ON V _{IN1} = 2 V or V _{IN1} = 3 V		1	2.6		4.2		4.5	mA
Negative Supply Current	I ₋			1	-1.3	-2		-2.2		mA
Reference Supply Current	I _R			1	-1.4	-2.2		-2.4		mA
Positive Supply Current	I ₊	All Channels OFF V _{IN1} = V _{IN2} = 0.8 V		1	0.75		25		25	μA
Negative Supply Current	I ₋			1	-1	-25		-25		μA
Reference Supply Current	I _R			1	0.5	-25		-25		μA

ELECTRICAL CHARACTERISTICS^a
DG144

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 12 \text{ V}$ $V_- = -18 \text{ V}$ $V_R = 0 \text{ V}$ $V_{IN2} = 2.5 \text{ V}$	LIMITS						UNIT	
			1=25°C 2=125,85°C 3=-55,-25°C	TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b		
SWITCH										
Analog Signal Range ^c	V_{ANALOG}		1,2,3		-10	10	-8	8	V	
Drain-Source ON Resistance	$r_{DS(ON)}$	$I_S = -10 \text{ mA}$ $V_{IN1} = 3 \text{ V}$ (SW1 ON) $V_{IN1} = 2 \text{ V}$ (SW2 ON)	$V_D = 10 \text{ V}$	1,3 2	20		30 60		Ω	
			$V_D = 8 \text{ V}$	1,3 2	35			50 75		
Source OFF Leakage Current	$I_{S(OFF)}$	$V_S = 10 \text{ V}$ $V_D = -10 \text{ V}$ $V_{IN1} = 2 \text{ V}$ (SW1 OFF) $V_{IN1} = 3 \text{ V}$ (SW2 OFF)	$V_S = 8 \text{ V}$ $V_D = -8 \text{ V}$	1 2	0.75		1 100			
			$V_D = 10 \text{ V}$ $V_S = -10 \text{ V}$	1 2	0.03		1 100			
Drain OFF Leakage Current	$I_{D(OFF)}$		$V_D = 8 \text{ V}$ $V_S = -8 \text{ V}$	1 2	0.15			5 100		
			$V_D = V_S = -10 \text{ V}$	1 2	-0.05	-2 -100				
Channel ON Leakage Current	$I_{D(ON)} + I_{S(ON)}$	$V_{IN1} = 3 \text{ V}$ (SW1 ON) $V_{IN1} = 2 \text{ V}$ (SW2 ON)	$V_D = V_S = -8 \text{ V}$	1 2	-0.12			-5 -100		
			$V_D = V_S = -10 \text{ V}$	1 2						
INPUT										
Input 1 Current Input 1 Voltage LOW	I_{IN1L}	$V_{IN1} = 2 \text{ V}$	1,3 2	0.001		0.1 2		4 4		
Input 2 Current Input 2 Voltage LOW	I_{IN2L}	$V_{IN2} = 2 \text{ V}, V_{IN1} = 2.5 \text{ V}$	1,3 2	0.001		0.1 2		4 4		
Input 1 Current Input 1 Voltage HIGH	I_{IN1H}	$V_{IN1} = 3 \text{ V}$	1,2 3	20		60 120		100 150		
Input 2 Current Input 2 Voltage HIGH	I_{IN2H}	$V_{IN2} = 3 \text{ V}, V_{IN1} = 2.5 \text{ V}$	1,2 3	20		60 120		100 150		
DYNAMIC										
Turn-ON Time	t_{ON}	See Switching Time Test Circuit ^e	1	0.5		0.8		1		
Turn-OFF Time	t_{OFF}		1	1.0		1.6		2	μs	

Not Recommended for New Designs

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ELECTRICAL CHARACTERISTICS ^a

DG144

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 12 \text{ V}$ $V_- = -18 \text{ V}$ $V_R = 0 \text{ V}$ $V_{IN2} = 2.5 \text{ V}$	LIMITS						UNIT	
			1=25°C 2=125,85°C 3=-55,-25°C		A SUFFIX -55 to 125°C		B SUFFIX -25 to 85°C			
TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b	MAX ^b					
DYNAMIC (Cont'd)										
Drain-OFF Capacitance	$C_{D(OFF)}$	$f = 1 \text{ MHz}$	$V_D = 0 \text{ V}$ $I_S = 0$	1	2.4					pF
Source-OFF Capacitance	$C_{S(OFF)}$		$V_S = 0 \text{ V}$ $I_D = 0$	1	2.4					
Channel-ON Capacitance	$C_{D(ON)} + C_{S(ON)}$		$V_D = V_S = 0 \text{ V}$	1	2.8					
OFF Isolation			$R_L = 75 \Omega$, $f = 1 \text{ MHz}$	1	>60					dB
SUPPLY										
Positive Supply Current	I_+	One Channel ON $V_{IN1} = 2 \text{ V}$ or $V_{IN1} = 3 \text{ V}$		1	2.6			4.2		4.5
Negative Supply Current	I_-			1	-1.3	-2			-2.2	
Reference Supply Current	I_R			1	-1.4	-2.2			-2.4	
Positive Supply Current	I_+	All Channels OFF $V_{IN1} = V_{IN2} = 0.8 \text{ V}$		1	0.75		25			25
Negative Supply Current	I_-			1	-1	-25			-25	
Reference Supply Current	I_R			1	-0.5	-25			-25	

ELECTRICAL CHARACTERISTICS ^a

DG146

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 12 \text{ V}$ $V_- = -18 \text{ V}$ $V_R = 0 \text{ V}$ $V_{IN2} = 2.5 \text{ V}$	LIMITS						UNIT	
			1=25°C 2=125,85°C 3=-55,-25°C		A SUFFIX -55 to 125°C		B SUFFIX -25 to 85°C			
TEMP	TYP ^d	MIN ^b	MAX ^b	MIN ^b	MAX ^b					
SWITCH										
Analog Signal Range ^c	V_{ANALOG}		1,2,3		-10	10	-8	8	V	
Drain-Source ON Resistance	$r_{DS(ON)}$	$I_S = -10 \text{ mA}$ $V_{IN1} = 3 \text{ V}$ (SW1 ON) $V_{IN1} = 2 \text{ V}$ (SW2 ON)	$V_D = 10 \text{ V}$	1, 2	7		10 20			Ω
			$V_D = 8 \text{ V}$	1, 2						

Not Recommended for New Designs

ELECTRICAL CHARACTERISTICS ^a

DG146

PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified: $V_+ = 12 \text{ V}$ $V_- = -18 \text{ V}$ $V_R = 0 \text{ V}$ $V_{N2} = 2.5 \text{ V}$	LIMITS						UNIT	
			1=25°C 2=125,85°C 3=-55,-25°C	A SUFFIX -55 to 125°C	B SUFFIX -25 to 85°C	TEMP	TYP ^c	MIN ^b	MAX ^b	
SWITCH (Cont'd)										
Source OFF Leakage Current	$I_{S(OFF)}$	$V_{IN1} = 2 \text{ V}$ (SW1 OFF) $V_{IN1} = 3 \text{ V}$ (SW2 OFF)	$V_S = 10 \text{ V}$ $V_D = -10 \text{ V}$	1 2	0.1			10 1000		nA
			$V_S = 8 \text{ V}$ $V_D = -8 \text{ V}$	1 2						
Drain OFF Leakage Current	$I_{D(OFF)}$	$V_D = 10 \text{ V}$ $V_S = -10 \text{ V}$ $V_D = 8 \text{ V}$ $V_S = -8 \text{ V}$	$V_D = 10 \text{ V}$ $V_S = -10 \text{ V}$	1 2	0.1			10 1000		nA
			$V_D = 8 \text{ V}$ $V_S = -8 \text{ V}$	1 2						
Channel ON Leakage Current	$I_{D(ON)} + I_{S(ON)}$	$V_{IN1} = 3 \text{ V}$ (SW1 ON) $V_{IN1} = 2 \text{ V}$ (SW2 ON)	$V_D = V_S = -10 \text{ V}$	1 2	-0.04	-2 -100				nA
			$V_D = V_S = -8 \text{ V}$	1 2						
INPUT										
Input 1 Current Input 1 Voltage LOW	I_{IN1L}	$V_{N1} = 2 \text{ V}$	1,3 2	0.001			0.1 2		4 4	μA
Input 2 Current Input 2 Voltage LOW	I_{IN2L}	$V_{IN2} = 2 \text{ V}, V_{IN1} = 2.5 \text{ V}$	1,3 2	0.001			0.1 2		4 4	
Input 1 Current Input 1 Voltage HIGH	I_{IN1H}	$V_{IN1} = 3 \text{ V}$	1,2 3	20			60 120		100 150	
Input 2 Current Input 2 Voltage HIGH	I_{IN2H}	$V_{IN2} = 3 \text{ V}, V_{IN1} = 2.5 \text{ V}$	1,2 3	20			60 120		100 150	
DYNAMIC										
Turn-ON Time	t_{ON}	See Switching Time Test Circuit ^e		1	0.5		1		1.5	μs
Turn-OFF Time	t_{OFF}			1	1.2		2.5		2.5	
Drain-OFF Capacitance	$C_{D(OFF)}$	$f = 1 \text{ MHz}$	$V_D = 0 \text{ V}$ $I_S = 0$	1	3					pF
Source-OFF Capacitance	$C_{S(OFF)}$		$V_S = 0 \text{ V}$ $I_D = 0$	1	3					
Channel-ON Capacitance	$C_{D(ON)} + C_{S(ON)}$		$V_D \approx V_S = 0 \text{ V}$	1	2.8					
OFF Isolation		$R_L = 75 \Omega, f = 1 \text{ MHz}$		1	>50					dB

Not Recommended for New Designs

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ELECTRICAL CHARACTERISTICS^a

DG146

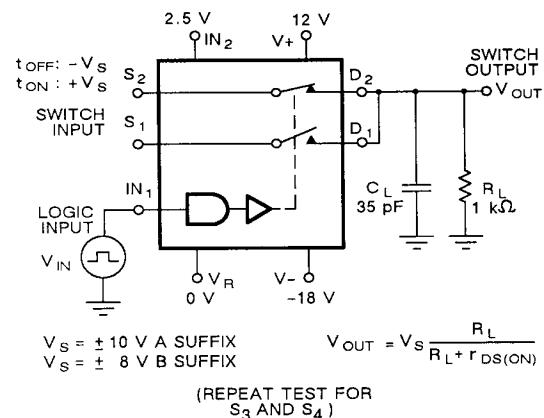
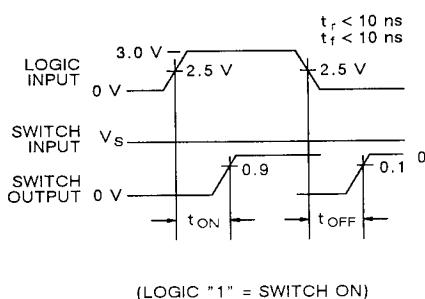
PARAMETER	SYMBOL	Test Conditions Unless Otherwise Specified:		LIMITS				UNIT
		V ₊ = 12 V	V ₋ = -18 V	TEMP	TYP ^d	MIN ^b	MAX ^b	
SUPPLY								
Positive Supply Current	I ₊	One Channel ON V _{IN1} = 2 V or V _{IN1} = 3 V	1	2.6		4.2		4.5
Negative Supply Current	I ₋		1	-1.2	-2		-2.2	
Reference Supply Current	I _R		1	-1.4	-2.2		-2.4	
Positive Supply Current	I ₊	All Channels OFF V _{IN1} = V _{IN2} = 0.8 V	1	0.75		25		25
Negative Supply Current	I ₋		1	-1	-25		-25	
Reference Supply Current	I _R		1	-0.5	-25		-25	

NOTES:

- a. Refer to PROCESS OPTION FLOWCHART for additional information.
 b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
 c. Guaranteed by design, not subject to production test.
 d. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
 e. V_{IN} must be a step function with a minimum rise and fall time of 1 V/μs.

SWITCHING TIME TEST CIRCUIT

Switch output waveform shown for V_S = constant with logic input waveform as shown. Note that V_S may be + or - as per switching time test circuit. V_O is the steady state output with switch ON. Feedthrough via gate capacitance may result in spikes at leading and trailing edge of output waveform.



Not Recommended for New Designs

APPLICATION HINTS

V ₊ Positive Supply Voltage (V)	V ₋ Negative Supply Voltage (V)	V _R Reference Voltage (V)	V _{IN1} Input 1 Voltage V _{INH} /V _{INL} (V)	V _{IN2} Input 2 Voltage (V)	V _S or V _D Analog Voltage Range (V)
12	-18	0	3/2	2.5	-10 to 10
15	-15	0	3/2	2.5	-7 to 13
10	-15	0	3/2	2.5	-7 to 8